

Phase Control Thyristors (Hockey PUK Version), 560 A



B-PUK (TO-200AC)

PRIMARY CHARACTERISTICS				
I _{T(AV)}	560 A			
V _{DRM} /V _{RRM}	400 V, 800 V, 1200 V, 1600 V, 1800 V, 2000 V			
V_{TM}	2.18 V			
I _{GT}	100 mA			
T_J	-40 °C to +125 °C			
Package	B-PUK (TO-200AC)			
Circuit configuration	Single SCR			

FEATURES

- · Center amplifying gate
- Metal case with ceramic insulator
- International standard case B-PUK (TO-200AC)



- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

- DC motor controls
- Controlled DC power supplies
- AC controllers

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
L		560	A			
I _{T(AV)}	T _{hs}	55	°C			
L		1115	А			
I _{T(RMS)}	T _{hs}	25	°C			
	50 Hz	8000	^			
I _{TSM}	60 Hz	8380	A			
l ² t	50 Hz	320	- kA ² s			
I=1	60 Hz	292	KA-S			
V _{DRM} /V _{RRM}		400 to 2000	V			
tq	Typical	100	μs			
TJ		-40 to 125	°C			

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS								
TYPE NUMBER	VOLTAGE CODE	V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	$\begin{aligned} I_{DRM}/I_{RRM}MAXIMUM\\ ATT_J = T_J\\ MAXIMUMmA \end{aligned}$				
	04	400	500					
08 VS-ST300CL		800	900					
		1200	1300	50				
VO 010000L	16	1600	1700	30				
18		1800	1900					
	20	2000	2100					



ABSOLUTE MAXIMUM RATINGS						•
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average on-state current	1	180° condu	ction, half sine v	vave	560 (275)	Α
at heatsink temperature	I _{T(AV)}	double side	(single side) co	oled	55 (75)	°C
Maximum RMS on-state current	I _{T(RMS)}	DC at 25 °C	heatsink tempe	erature double side cooled	1115	
		t = 10 ms	No voltage		8000	A kA ² s
Maximum peak, one-cycle		t = 8.3 ms	reapplied		8380	
non-repetitive surge current	I _{TSM}	t = 10 ms	100 % V _{RRM}	Sinusoidal half wave, initial $T_J = T_J$ maximum	6730	
		t = 8.3 ms	reapplied		7040	
Maximum I ² t for fusing		t = 10 ms	t = 8.3 ms reapplied		320	
	l ² t	t = 8.3 ms			292	
		t = 10 ms			226	
		t = 8.3 ms	reapplied		207	
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied			3200	kA²√s
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π	(16.7 % x π x $I_{T(AV)}$ < I < π x $I_{T(AV)}$), $T_J = T_J$ maximum			V
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi \times I_{T(AV)})$	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			V
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$), $T_J = T_J$ maximum			0.74	mΩ
High level value of on-state slope resistance	r _{t2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			0.73	1115.2
Maximum on-state voltage	V_{TM}	$I_{pk} = 1635 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$			2.18	٧
Maximum holding current	I _H	T 05 00	T 0500 1 1 101/ 111 1			mA
Typical latching current	ΙL	T _J = 25 °C, anode supply 12 V resistive load			1000	IIIA

SWITCHING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum non-repetitive rate of rise of turned-on current	dI/dt	Gate drive 20 V, 20 Ω , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%~V_{DRM}$	1000	A/μs		
Typical delay time	t _d	Gate current 1 A, $dl_g/dt = 1 A/\mu s$ $V_d = 0.67 \% V_{DRM}, T_J = 25 °C$	1.0			
Typical turn-off time	t _q	I_{TM} = 550 A, T_J = T_J maximum, dl/dt = 40 A/μs, V_R = 50 V, dV/dt = 20 V/μs, gate 0 V 100 Ω , t_p = 500 μs	100	μs		

BLOCKING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum critical rate of rise of off-state voltage	dV/dt	T _J = T _J maximum linear to 80 % rated V _{DRM}	500	V/µs	
Maximum peak reverse and off-state leakage current	I _{RRM,} I _{DRM}	$T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied	50	mA	



TRIGGERING						
DADAMETED	CVMDOL	TEST CONDITIONS		VALUES		шито
PARAMETER	SYMBOL			TYP.	MAX.	UNITS
Maximum peak gate power	P _{GM}	$T_J = T_J$ maximum,	$t_p \le 5 \text{ ms}$	10.0		w
Maximum average gate power	P _{G(AV)}	$T_J = T_J$ maximum,	f = 50 Hz, d% = 50	2	.0	VV
Maximum peak positive gate current	I _{GM}	$T_J = T_J$ maximum,	$t_p \le 5 \text{ ms}$	3	.0	Α
Maximum peak positive gate voltage	+ V _{GM}	T. T 12 1 1 1.		20		V
Maximum peak negative gate voltage	- V _{GM}	$T_J = T_J$ maximum, $t_p \le 5$ ms			.0	V
		T _J = - 40 °C	Maximum required gate trigger/ current/voltage are the lowest	200	-	
DC gate current required to trigger	I _{GT}	T _J = 25 °C		100	200	mA
		T _J = 125 °C		50	-	
		$T_J = -40 ^{\circ}\text{C}$ value which will trigger all units	2.5	-		
DC gate voltage required to trigger	V_{GT}	T _J = 25 °C	12 V anode to cathode applied	1.8	3.0	V
		T _J = 125 °C		1.1	-	
DC gate current not to trigger	I_{GD}		Maximum gate current/	10	0.0	mA
DC gate voltage not to trigger	V_{GD}	$T_J = T_J$ maximum	voltage not to trigger is the maximum value which will not trigger any unit with rated V _{DRM} anode to cathode applied		0.25	

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum operating junction temperature range	T_J		-40 to 125	- °C	
Maximum storage temperature range	T _{Stg}		-40 to 150		
Maximum thermal resistance, junction to heatsink	D	DC operation single side cooled	0.11		
maximum thermal resistance, junction to heatslink	R _{thJ-hs}	DC operation double side cooled	0.05	K/W	
Maximum thormal registance, ages to be striple	R _{thC-hs}	DC operation single side cooled	0.011		
Maximum thermal resistance, case to heatsink		DC operation double side cooled	0.006		
Mounting force, ± 10 %			9800	N	
Woulding force, ± 10 %			(1000)	(kg)	
Approximate weight			250	g	
Case style		See dimensions - link at the end of datasheet	B-PUK (TO-2	200AC)	

△R _{thJ-hs} CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION		RECTANGULAR CONDUCTION		TEST CONDITIONS	UNITS
CONDUCTION ANGLE	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE	TEST CONDITIONS	UNITS
180°	0.012	0.010	0.008	0.008	$T_J = T_J$ maximum	K/W
120°	0.014	0.015	0.014	0.014		
90°	0.018	0.018	0.019	0.019		
60°	0.026	0.027	0.027	0.028		
30°	0.045	0.046	0.046	0.046		

Note

• The table above shows the increment of thermal resistance RthJ-hs when devices operate at different conduction angles than DC

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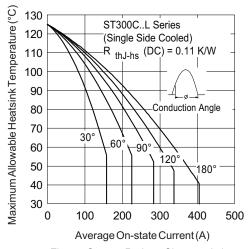


Fig. 1 - Current Ratings Characteristics

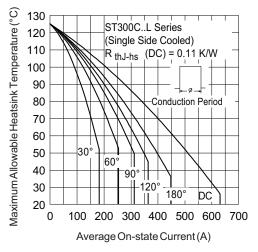


Fig. 2 - Current Ratings Characteristics

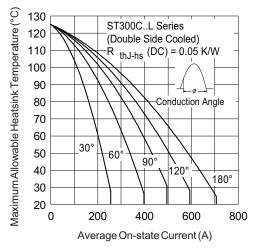


Fig. 3 - Current Ratings Characteristics

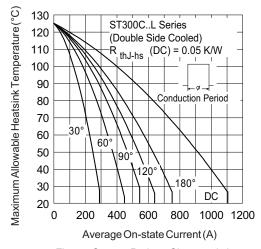


Fig. 4 - Current Ratings Characteristics

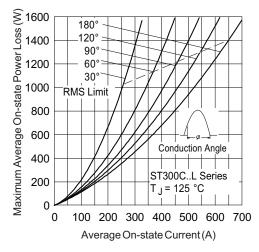


Fig. 5 - On-State Power Loss Characteristics

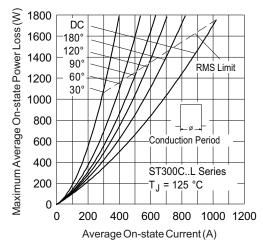
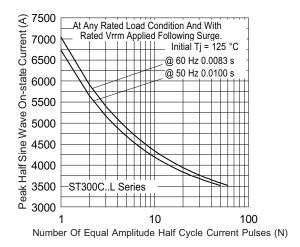


Fig. 6 - On-State Power Loss Characteristics



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Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

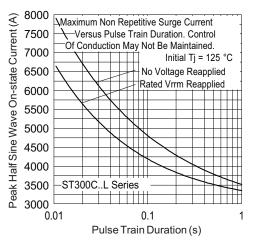


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

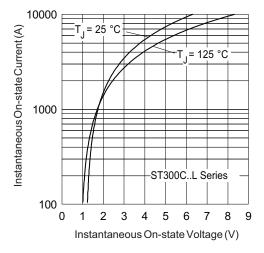


Fig. 9 - On-State Voltage Drop Characteristcs

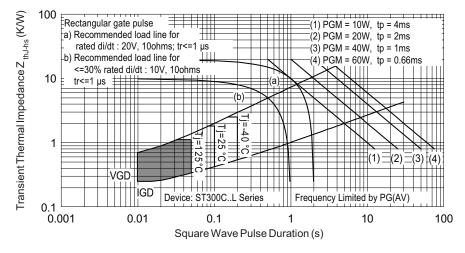


Fig. 1 - Thermal Impedance Z_{thJ-hs} Characteristics

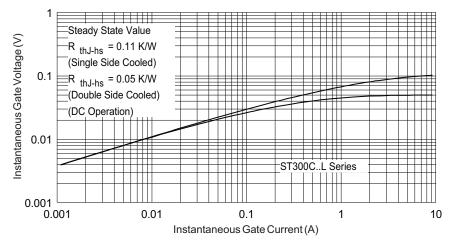
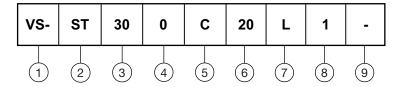


Fig. 10 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Thyristor

3 - Essential part number

4 - 0 = converter grade

5 - C = ceramic PUK

6 - Voltage code x 100 = V_{RRM} (see Voltage Ratings table)

7 - L = PUK case B-PUK (TO-200AC)

8 - 0 = eyelet terminals (gate and auxiliary cathode unsoldered leads)

1 = fast-on terminals (gate and auxiliary cathode unsoldered leads)

2 = eyelet terminals (gate and auxiliary cathode soldered leads)

3 = fast-on terminals (gate and auxiliary cathode soldered leads)

9 - Critical dV/dt: • None = 500 V/µs (standard selection)

• L = 1000 V/µs (special selection)

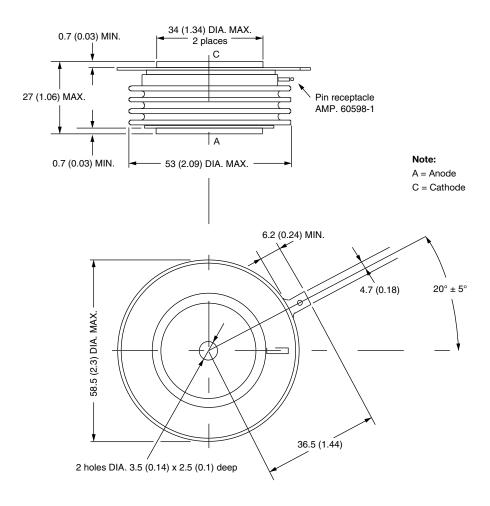
LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95076		



B-PUK (TO-200AC)

DIMENSIONS in millimeters (inches)

Creepage distance: 36.33 (1.430) minimum Strike distance: 17.43 (0.686) minimum



Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)



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